



MAINTENANCE MANUAL 851-870 MHz, 100 WATT POWER AMPLIFIER 19D901841G2

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DESCRIPTION

The 800 MHz power amplifier assembly used in station applications uses five RF power transistors to provide a maximum of 100 watts output power. R11 on the Power Control Board (19D901803G3) provides adjustment of the output power over a 10 dB range (10W to 100W).

The power amplifier assembly consists of an RF board with all the amplifier stages and an output detector, a power control board, and an isolator.

Supply voltage from the system board is connected to TB1 and decoupled by C6.

CIRCUIT ANALYSIS

POWER AMPLIFIER

The exciter output (65-130 mW) is coupled to the amplifier input connector J1 by a 50 ohm coaxial cable. L1, C1,

C2, and the base microstrip form the input matching circuit for Q1. Control voltage is applied to Q1 through a collector feed network consisting of C3, C4, and L3.

Interstage matching between Q1 and Q2 is provided by L4, L5, C6, C8, C9, and C10. Control voltage is applied to Q2 through a collector feed network consisting of Z1, C11-C13, and L7. The output of Q2 is matched to the input of Q3 by L8, L9, C30, C15, and the base microstrip.

Supply voltage for Q3 is applied through collector feed network Z2, C16-C18, and L11. The output of Q3 is matched to 50 ohms by microstrip W2. This output is applied to a Wilkinson divider consisting of microstrips W4 and W5. R1 provides isolation between the signal paths.

Input matching for Q4 and Q5 is provided by microstrips W8 and W9. Supply voltage is applied to Q4 and Q5 by collector feed networks Z3, Z4, C20-C25, L12, and L13. Microstrips W12 and W13 provide output matching.

The outputs of Q4 and Q5 are summed by a Wilkinson combiner consisting of W16, W17, and R3. The output of the combiner is connected to pin 1 of circulator U1.



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LBI-38134

A directional coupler, W19, and detector CR1 provide a voltage, proportional to the power out, to the power control.

WARNING

The RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic, or other encapsulation is opened, crushed, broken, or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

– NOTE -

This amplifier is <u>not</u> field repairable. Should service become necessary, the complete power amplifier assembly must be returned to the factory for servicing.

POWER CONTROL

On the Power Control Board, the voltage from the detector is compared to a stable DC reference voltage in a high gain comparator, U2A. The comparator drives a DC amplifier, Q4 and pass transistor Q6 that supplies control voltage to the RF board.

Thermistor RT1 is connected to the PA heatsink and, by controlling the operation of Q2 and Q3, provides a power cut-back for ambient temperatures that exceed 70 degrees centigrade. Conduction of Q3 gradually decreases the power set voltage applied to Q4. The DC reference voltage is provided by Q1, U3, R17-19, and C5.

In other special applications of this power control board, U2-B, CR1, and Q5 provide a low power alarm. U1 is used to select one of four individually adjustable power levels.

R1, R4, R7, and R10 are factory adjusted values.

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851-870 MHZ 100 WATT POWER AMPLIFIER 19D901841G2

| 19D901841G2 | | | | |
|--------------------|---------------|---|--|--|
| SYMBOL | PARTS LIST | DESCRIPTION | | |
| A 1 | | POWER AMPLIFIER BOARD 19D901807G3 | | |
| | | CAPACITORS | | |
| C1 | 19A702232P12 | Ceramic: 9.1 pF ±5%, 50 VDCW. | | |
| C2 | 19A705108P13 | Mica Chip: 10 pF ±5%, 500 VDCW, temp coef 0 + 200 PPM/°C. | | |
| C3 | 19A702232P31 | Ceramic: 56 pF ±5%, 50 VDCW. | | |
| C4 | 19A702250P113 | Polyester: 0.1 μF ±10%, 50 VDCW. | | |
| C6 | 19A702232P3 | Ceramic: 3.9 pF ±.25 pF, 50 VDCW. | | |
| C7 | 19A702232P31 | Ceramic: 56 pF ±5%, 50 VDCW. | | |
| C8 | 19A705108P13 | Mica Chip: 10 pF ±5%, 500 VDCW, | | |
| C9 and C10 | 19A705108P13 | temp coef 0 + 200 PPM/°C. Mica Chip: 10 pF ±5%, 500 VDCW, temp coef 0 + 200 PPM/°C. | | |
| C11 | 19A702232P31 | Ceramic: 56 pF ±5%, 50 VDCW. | | |
| C12 | 19A702250P113 | Polyester: 0.1 μF ±10%, 50 VDCW. | | |
| C13 | 19A701534P6 | Tantalum: 4.7 μF ±20%, 35 VDCW. | | |
| C14 | 19A702232P31 | Ceramic: 56 pF ±5%, 50 VDCW. | | |
| C15 | 19A705108P9 | Mica: 6.8 pF ±.25 pF, 500 VDCW. | | |
| C16 | 19A705108P25 | Mica Chip: 33 pF ±5%, 500 VDCW, temp coef 0 + 50 PPM/°C. | | |
| C17 | 19A702250P113 | Polyester: 0.1 μF ±10%, 50 VDCW. | | |
| C18 | 19A701534P6 | Tantalum: 4.7 μF ±20%, 35 VDCW. | | |
| C19 | 19A702232P31 | Ceramic: 56 pF ±5%, 50 VDCW. | | |
| C20 and C21 | 19A705108P25 | Mica Chip: 33 pF \pm 5%, 500 VDCW, temp coef 0 + 50 PPM/C. | | |
| C22 | 19A701534P6 | Tantalum: 4.7 μF ±20%, 35 VDCW. | | |
| C23 and C24 | 19A702250P113 | Polyester: 0.1 μF ±10%, 50 VDCW. | | |
| C25 | 19A701534P6 | Tantalum: 4.7 μF ±20%, 35 VDCW. | | |
| C26 and C27 | 19A702232P31 | Ceramic: 56 pF ±5%, 50 VDCW. | | |
| C28 | 19A702232P21 | Ceramic: 22 pF ±5%, 50 VDCW. | | |
| C29 | 19A702232P1 | Ceramic: 3.3 pF ±.25 pF, 50 VDCW. | | |
| C30 | 19A705108P8 | Mica: 6.2 pF ±.25 pF, 500 VDCW. | | |
| C31 thru C35 | 19A705108P25 | Mica Chip: 33 pF ±5%, 500 VDCW, temp coef 0 + 50 PPM/°C. | | |
| | | DIODES | | |
| CR1 and CR2 | 19A700047P3 | Silicon: 100 mW; sim to 1N6263. | | |
| | | JACKS | | |
| J1 | 19A700049P2 | Connector, receptacle; 500 VDCW maximum; sim to NTTF-1058. | | |
| J2 J3 | 19A704852P32 | Part of Circulator U1. Printed wire, two part: 6 contacts, sim | | |
| J4 and J5 | 19A134263P1 | to Molex 22-29-2061. Contact, electrical: sim to Selectro 229-1082-00-0-590. | | |

| SYMBOL | PARTS LIST | DESCRIPTION |
|--------------------|---------------|---|
| | | INDUCTORS |
| L1 | | Part of printed wire board. |
| L2 | 19A701091G1 | Coil. |
| L3 | 19A701091G1 | Coil. |
| L4 | 19A701006P7 | Strap. |
| L5 | | Part of printed wire board. |
| L6 | 19A701091G1 | Coil. |
| L7 | 19A136533P2 | Coil. |
| L8 and L9 | | Part of printed wire board. |
| L10 | 19A701091G1 | Coil. |
| L11 thru L13 | 19A136533P2 | Coil. |
| | | TRANSISTORS |
| Q1 | 19A703479P1 | N Channel, field effect. sim to RF |
| Q2 | 19A703480P4 | 2060. Silicon, NPN: Sim to MRF-891. |
| Q3 | 19A705125P1 | Silicon, NPN: Sim to MRF-895. |
| Q4 and Q5 | 19A705125P2 | Silicon, NPN: Sim to MRF-898. |
| | | RESISTORS |
| R1 | 19A700111P39 | Composition: 100 ohms ± 5%, 2 w. |
| R2 | 19A700106P32 | Composition: 51 ohms ± 5%, 1/4 w. |
| R3 | 19A143832P1 | Power: 100 ohms ±5%, 75 w. |
| R4 | 19A700113P55 | Composition: 470 ohms ± 5%, 1/2 w. |
| R5 | H212CRP247C | Deposited carbon: 4.7K ohms ±5%, 1/4 w. |
| R6 | H212CRP310C | Deposited carbon: 10K ohms ±5%, 1/w. |
| R7 | 19A700106P55 | Composition: 470 ohms ± 5%, 1/4 w. |
| R8 | 19B800607P101 | Metal film: 100 ohms ±5%, 1/8 w. |
| | | INTEGRATED CIRCUITS —— |
| U1 | 19B802097P2 | Circulator: 120 watts. |
| | | CABLES |
| W1 thru W20 | | Part of printed wire board. |
| | | FILTER |
| Z1 thru Z4 | 19A701092G1 | Filter. |
| | 19B801426P2 | Support plate. |
| | 19B801426P1 | Support plate. |
| A2 | | POWER CONTROL BOARD 19D901803G3 |
| | | ——— CAPACITORS———— |
| C1 thru C4 | 19A700233P9 | Ceramic: 2200 pF ±20%, 50 VDCW. |

| SYMBOL | PARTS LIST | DESCRIPTION |
|-------------------|----------------------------|---|
| C5 | T644ACP310K | Polyester: .010 μF ±10%, 50 VDCW. |
| C6 | 19A701534P6 | Tantalum: 4.7 μF ±20%, 35 VDCW. |
| C7 | 19A701624P12 | Ceramic, disc: 15 pF ±5%, 500 VDCW, temp coef 0 PPM ±30. |
| C8 | 19A702250P113 | Polyester: 0.1 μF ±10%, 50 VDCW. |
| C9 | 19A701624P12 | Ceramic, disc: 15 pF ±5%, 500 VDCW, |
| thru C12 | | temp coef 0 PPM ±30. |
| C13 | 19A700233P6 | Ceramic: 680 pF ±20%, 50 VDCW. |
| | | DIODES |
| CR1 | 19A700028P1 | Silicon: 75 mA, 75 PIV; sim to 1N4148. |
| | | JACKS |
| J1 | 19A704852P31 | Connector: 5 contacts; sim to Molex 22- 29-2051. |
| J2 | 19A704852P32 | Printed wire, two part: 6 contacts, sim to Molex 22-29-2061. |
| J3 | 19A700072P1 | Printed wire: 2 contacts rated @ 2.5 amps; sim to Molex 22-03-2021. |
| | | TRANSISTORS |
| Q1 | 19A700023P2 | Silicon, NPN: sim to 2N3904. |
| Q2 | 19A700022P2 | Silicon, PNP: sim to 2N3906. |
| and Q3 | 10/11/000221/2 | G. 100001 |
| Q4 and Q5 | 19A700023P2 | Silicon, NPN: sim to 2N3904. |
| Q6 | 19A700055P1 | Silicon, PNP. (Included with Heat Sink Assembly 19B801427G4). |
| Q7 and Q8 | 19A700023P2 | Silicon, NPN: sim to 2N3904. |
| | | RESISTORS |
| R1 | 19A134248P4 | Variable, cermet, 4 turns: 25K ohms ±10%, 1/2 w; sim to Bourns 3339P-1-253. |
| R2 | 19B800779P10 | Variable: 10K ohms ±25%, 100 VDCW, .3 watt. |
| R3 | H212CRP210C | Deposited carbon: 1K ohms ±5%, 1/4 w |
| R4 | 19A134248P4 | Variable, cermet, 4 turns: 25K ohms |
| R5 | 19B800779P10 | ±10%,1/2 w; sim to Bourns 3339P-1-25 Variable: 10K ohms ±25%, 100 VDCW, |
| De | H212CDD240C | .3 watt. |
| R6 R7 | H212CRP210C 19A134248P4 | Deposited carbon: 1K ohms ±5%, 1/4 w Variable, cermet, 4 turns: 25K ohms |
| D0 | 10000770040 | ±10%, 1/2 w; sim to Bourns 3339P-1- 253. |
| R8 | 19B800779P10 | Variable: 10K ohms ±25%, 100 VDCW, .3 watt. |
| R9 | H212CRP210C | Deposited carbon: 1K ohms ±5%, 1/4 w |
| R10 | 19A134248P4 | Variable, cermet, 4 turns: 25K ohms ±10%, 1/2 w; sim to Bourns 3339P-1-253. |
| R11 | 19B800779P10 | Variable: 10K ohms ±25%, 100 VDCW, .3 watt. |
| R12 | H212CRP210C | Deposited carbon: 1K ohms ±5%, 1/4 w |
| R13 and R14 | H212CRP310C | Deposited carbon: 10K ohms $\pm 5\%$, 1/4 w. |
| R15 | H212CRP415C | Deposited carbon: 0.15M ohms ±5%, |
| R16 | H212CRP368C | 1/4 w. Deposited carbon: 68K ohms ±5%, 1/4 |
| R17 | 19A701250P239 | w. Metal film: 2490 ohms ±1%, 250 VDCW |

| SYMBOL | PARTS LIST | DESCRIPTION |
|------------|---------------|--|
| R18 | 19A701250P295 | Metal film: 9.53K ohms ±1%, 1/4 w. |
| R19 | H212CRP168C | Deposited carbon: 680 ohms ±5%, 1/4 w. |
| R20 | H212CRP310C | Deposited carbon: 10K ohms ±5%, 1/4 w. |
| and R21 | | |
| R22 | H212CRP247C | Deposited carbon: 4.7K ohms ±5%, 1/4 |
| R23 | H212CRP222C | w. Deposited carbon: 2.2K ohms ±5%, 1/4 |
| R24 | H212CRP310C | w. Deposited carbon: 10K ohms ±5%, 1/4 w. |
| R25 | H212CRP233C | Deposited carbon: 3.3K ohms ±5%, 1/4 |
| R26 | H212CRP239C | w. Deposited carbon: 3.9K ohms ±5%, 1/4 w. |
| R27 | H212CRP218C | Deposited carbon: 1.8K ohms ±5%, 1/4 w. |
| R28 | H212CRP256C | Deposited carbon: 5.6K ohms ±5%, 1/4 w. |
| R29 | H212CRP227C | Deposited carbon: 2.7K ohms ±5%, 1/4 w. |
| R30 | H212CRP268C | Deposited carbon: 6.8K ohms ±5%, 1/4 w. |
| R31 | H212CRP210C | Deposited carbon: 1K ohms ±5%, 1/4 w. |
| R32 | H212CRP147C | Deposited carbon: 470 ohms ±5%, 1/4 w. |
| R33 | 19A143832P | Power: 50 ohms ±5%, 150 watts. (Used with A3). |
| R34 | H212CRP439C | Deposited carbon: 0.39M ±5%, 1/4 w. |
| R35 | H212CRP347C | Deposited carbon: 47K ohms ±5%, 1/4 w. |
| | | THERMISTOR |
| RT1 | 19A702176G2 | Thermistor: 40K ohms ±20%. |
| | | — INTEGRATED CIRCUITS —— |
| U1 | 19A700029P36 | Digital: Single 8-Channel Multiplexer; sim to 4051B. |
| U2 | 19A701789P2 | Linear: Dual Op Amp; sim to LM358. |
| U3 | 19A702939P2 | Linear: Adjustable Shunt Regulator; sim to TL431CLP. |
| | | MISCELLANEOUS |
| | 19A702364P305 | Machine screw: TORX DRIVE, M35 x 5. |
| | 19B801427G4 | Heat Sink Assembly. Includes Q6 and: |
| | 19A700115P3 | Insulator, plate. |
| | 19A700068P1 | Insularor, bushing. |
| | 19B801428G3 | Heat Sink. |
| | N404P11B6 | Lockwasher; internal: No. 4. |
| | N402P5B6 | Washer: narrow, steel. |
| | N80P9005B6 | Machine screw: pan head, steel. |
| А3 | | PRINTED WIRE BOARD |
| | | CABLES |
| W1 | 19A705075P1 | Cable. |
| W2 | 19B801431P3 | Cable. |
| W3 | 19C851528G1 | Cable. (Includes Feed-thru Plate, connector P1 and associated hardware). |
| | | MISCELLANEOUS |
| | 19B801424G1 | Frame. |
| | 19B801423G3 | Plate. |
| | 19B226212G1 | Heat Sink. (Mounts on Plate, Qty of 4). |

^{*} COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

| SYMBOL | PARTS LIST | DESCRIPTION |
|--------|---------------|--|
| | 19B226212G5 | Heat Sink. (Mounts on Plate, Qty of 1). |
| | NP280071 | Nameplate. (CAUTION). |
| | 19B209103P410 | Tap screw, hex head: No. 8-32 x 5/8. |
| | 19B201074P308 | (Secures Heat Sink to plate). Tap screw, Phillips POZIDRIV: No. 6-3 x 1/2. (Used with A1, Q4, Q5 and ground strap). |
| | 19B209103P306 | Tap screw, hex head: No. 6-32 x 3/8. (Secures frame to plate). |
| | N403P13B6 | Lockwasher: No. 6. (Used with ground strap). |
| | N81P9012 | Machine screw, recessed pan: No. 4-4 x 3/4. |
| | N414P11 | Lockwasher, internal tooth: No. 4. (Used with Circulator). |
| | N44P9006B6 | Machine screw, fillister head. (Secures Q2-Q5). |
| | N405P5B6 | Lockwasher. (Used with Q2-Q5, R3 an R33). |
| | 5492178P2 | Washer, spring tension: sim to Wallace Barnes 375-20. (Used with Q1). |
| | 19A148323P1 | Heat Sink. (Used with Q1). |
| | N210P15B6 | Nut, hex: No. 8-32. (Used with Q1). |
| | N402P8B6 | Flatwasher, steel: No. 8. (Used with Q |
| | 19C851552P1 | Guide. (Used around potentiometers o A2). |
| | 19B201074P320 | Tap screw, Phillips POZIDRIV: No. 6-3 x 1-1/4. (Secures A2 Q6 Heat Sink). |
| | 19A705329P1 | Temperature indicator: sim to Tempil Division of Big Three Industries Cat. No BU-175/79. (Attached to A1 Q4). |
| | 19A116552P3 | Cable clip: sim to Richco KKC-4. (Supports W3). |
| | 19A705097G1 | Support. (Used with input connector J1 |
| | N80P13004B6 | Screw, machine: Pan head; No. 6-32 x 1/4". (Secures support). |
| | 19D438235G7 | Fan Assembly, 24 Vdc. |
| | 19A701863P13 | Cable clip. (Secures fan assembly wiring). |
| | 7141225P2 | Nut, Hex: 4-40. (Secures cable clip). |
| | N80P13006B6 | Machine screw: Pan head, Phillips; No 8-32 x 3/8" |
| | N404P13B6 | Lockwasher, internal tooth: No. 6. |
| | N402P7B6 | Flatwasher, narrow: No. 6. |
| | 7141225P3 | Hex Nut: No. 6-32. |
| | N80P9005B6 | Machine screw, pan head, steel, No. 4 40UNC x 5/16". |
| İ | N402P5B6 | Washer: narrow, steel. |
| i | N404P11B6 | Loackwasher, internal tooth, No. 4. |

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter" which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for the descriptions of parts affected by these revisions.

REV. A - POWER AMPLIFIER 19D901807G3

To allow maximum power transfer from the exciter, changed C2 and L4, deleted R6 and added R7.

C2 was 19A705108P15 Mica: 12pF ±5%, 500 VDCW. L4 was 19A701006P6 Strap. R6 was H212CRP310C Deposited carbon: 10K ±5%, 1/4 w.

REV. B - POWER AMPLIFIER 19D901807G3

To improve power cutoff when no RF is present at the input. Changed R5 and added R6.

R5 was H212CRP318C Deposited carbon: 18K \pm 5%, 1/4 w.

REV. C - POWER AMPLIFIER 19D901807G3

To improve stability, added R8.

REV. A - POWER CONTROL BOARD 19D901803G3

To allow alarming of a low or missing drive level to the Power Amplifier, changed R15, R16, R35 and Q8. Changed R34 and relocated as shown below. Also changed R1, R4, R7 and R10 from a 1 turn potentiometer to a 4 turn potentiometer.

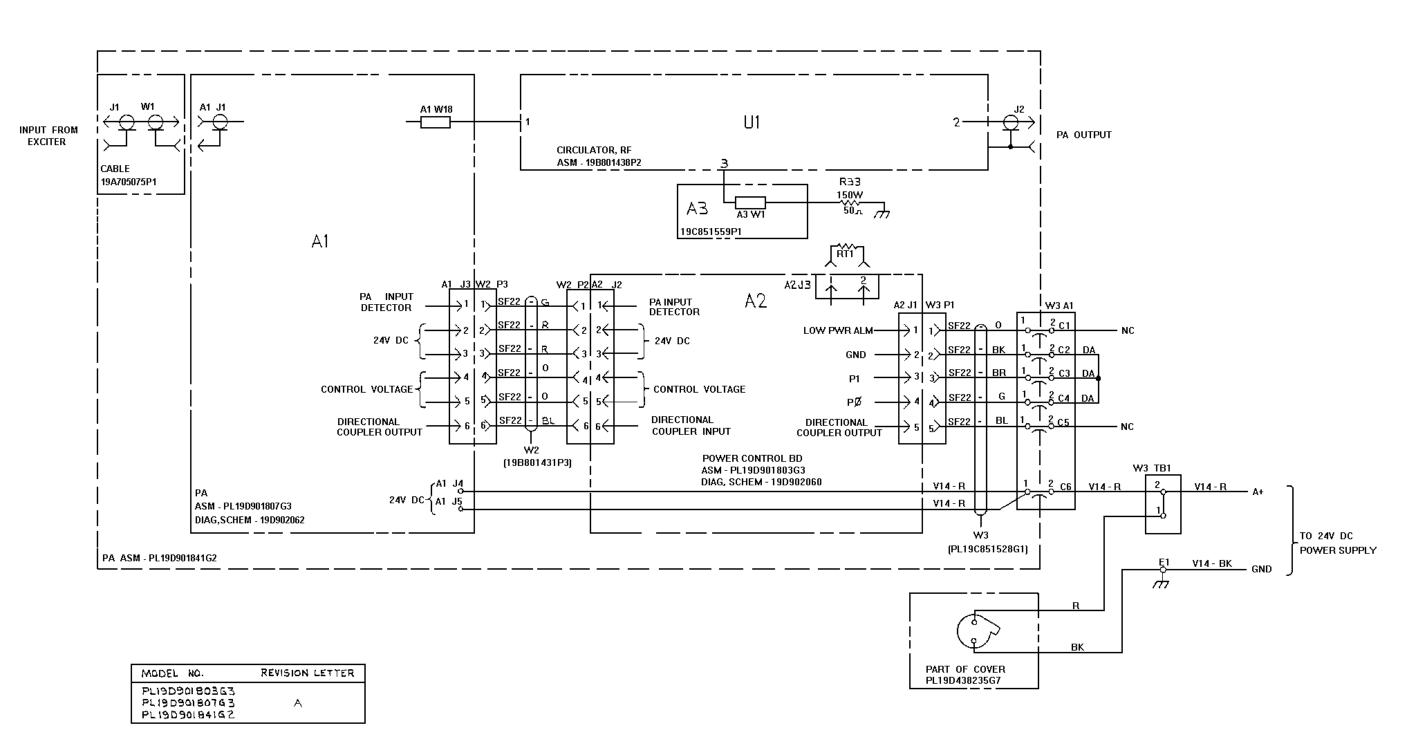
R1 is 19A134248P4 - Variable, cermet, 4 turns: 25K ohms $\pm 10\%$, 1/2 w; sim to Bourns 3339P-1-253.

R4 is 19A134248P4 - Variable, cermet, 4 turns: 25K ohms $\pm 10\%,\,1/2$ w; sim to Bourns 3339-1-253.

R7 is 19A134248P4 - Variable, cermet, 4 turns: 25K ohms $\pm 10\%$, 1/2 w; sim to Bourns 3339P-253.

R10 is 19A134248P4 - Variable, cermet, 4 turns: 25K ohms $\pm 10\%$, 1/2 w; sim to Bourns 3339P-1-253.

R15 is H212CRP415C - Deposited carbon: .15M ohms \pm 5%, 1/4 w. R16 is H212CRP368C - Deposited carbon: .68K ohms \pm 5%, 1/4 w. R34 is H212CRP439C - Deposited carbon: .39M ohms \pm 5%, 1/4 w. R35 is H212CRP347C - Deposited carbon: .47K ohms \pm 5%, 1/4 w. Q8 is 19A700023P2 - Silicon, NPN: sim to 2N3904.

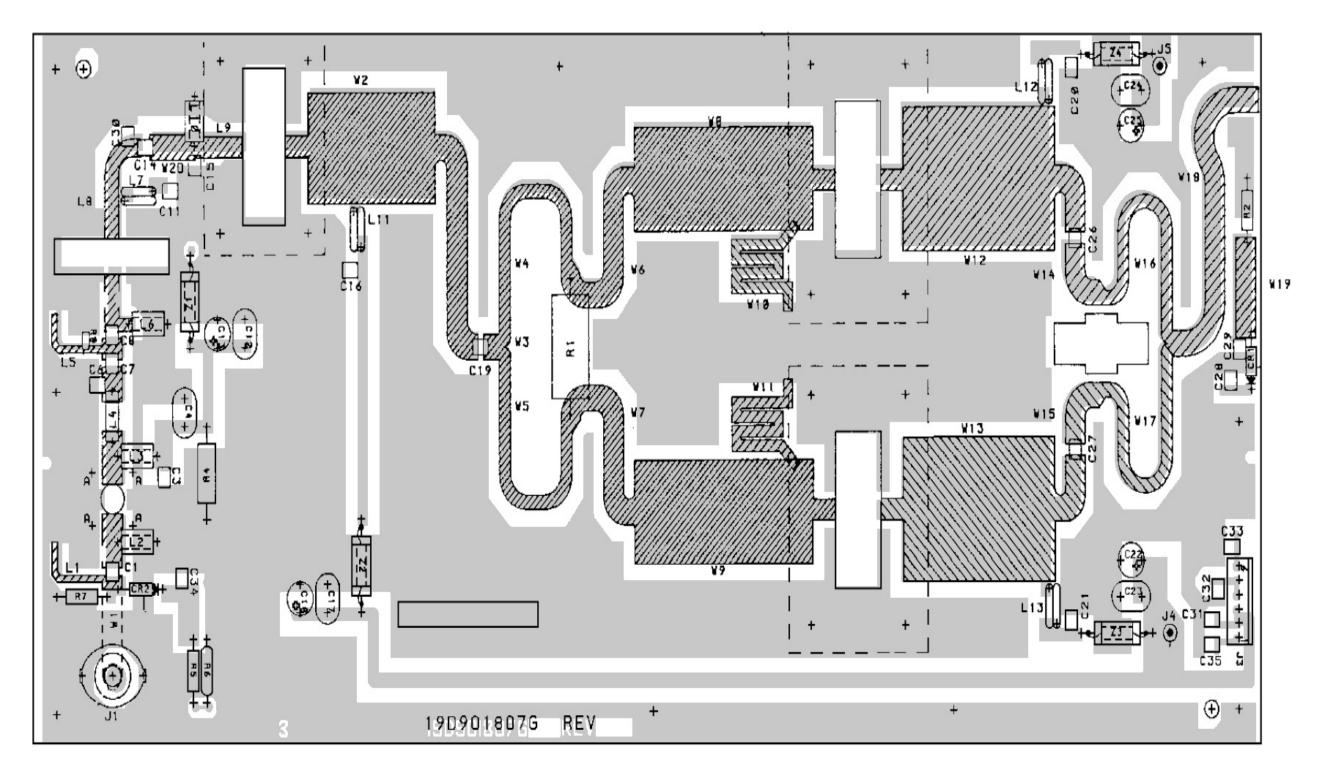


POWER AMPLIFIER

19D901841G2

(19D902064, Sh. 1, Rev. 1)

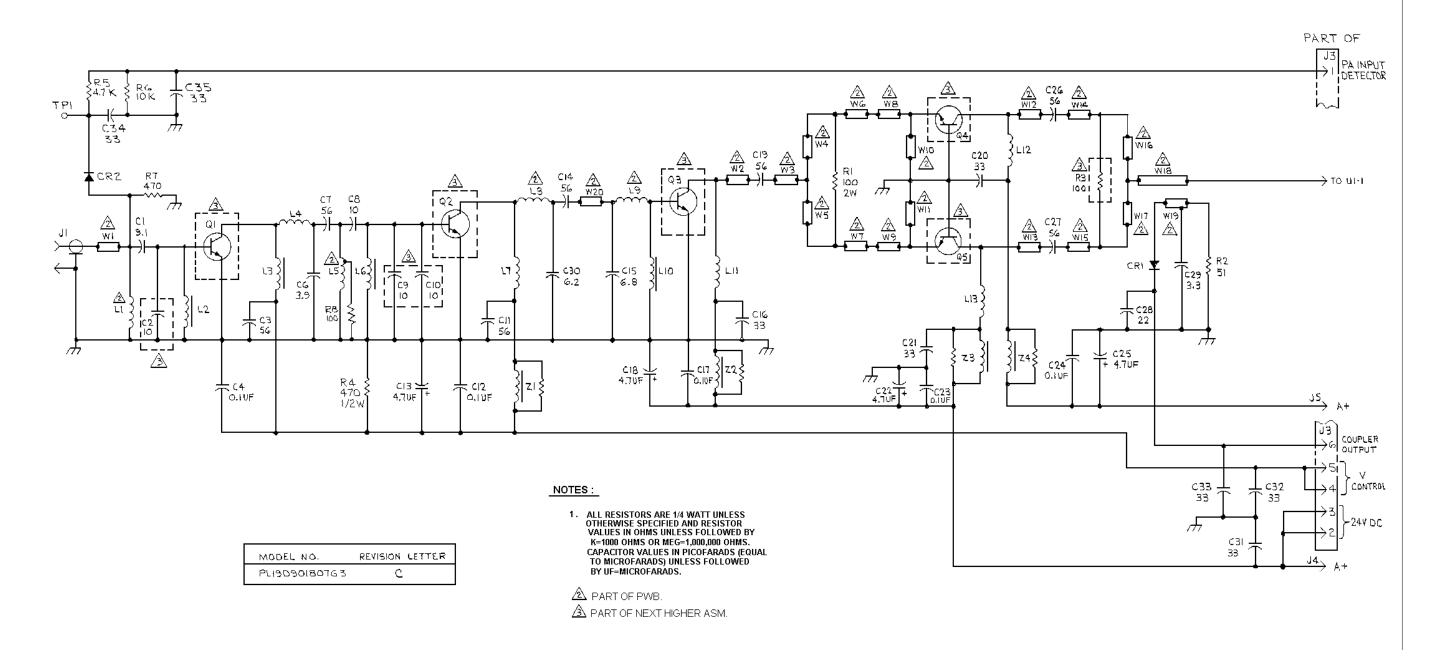
COMPONENT SIDE



POWER AMPLIFIER

19D901807G3

⁽¹⁹D901807, Sh. 2, Rev. 6) (19D705468, Sh. 1, Rev. 3) (19A705468, Sh. 2, Rev. 1)



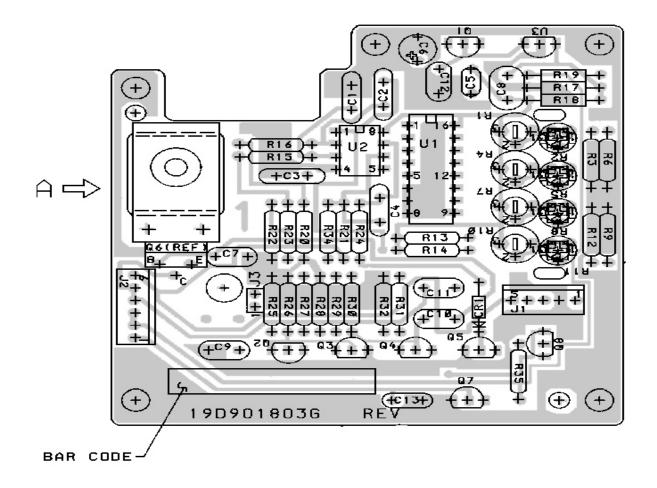
POWER AMPLIFIER

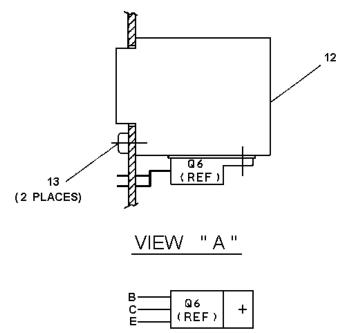
19D901807G3

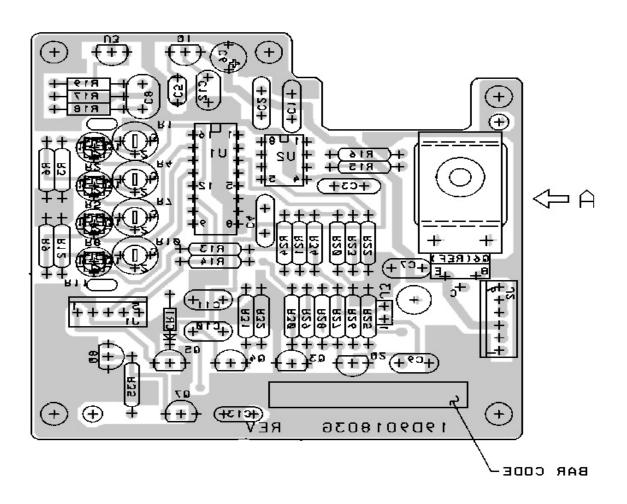
(19D902062, Rev. 4)

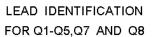
COMPONENT SIDE

SOLDER SIDE











TOP VIEW

NOTE: CASE SHAPE IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

LEAD IDENTIFICATION FOR U3



IN - LINE

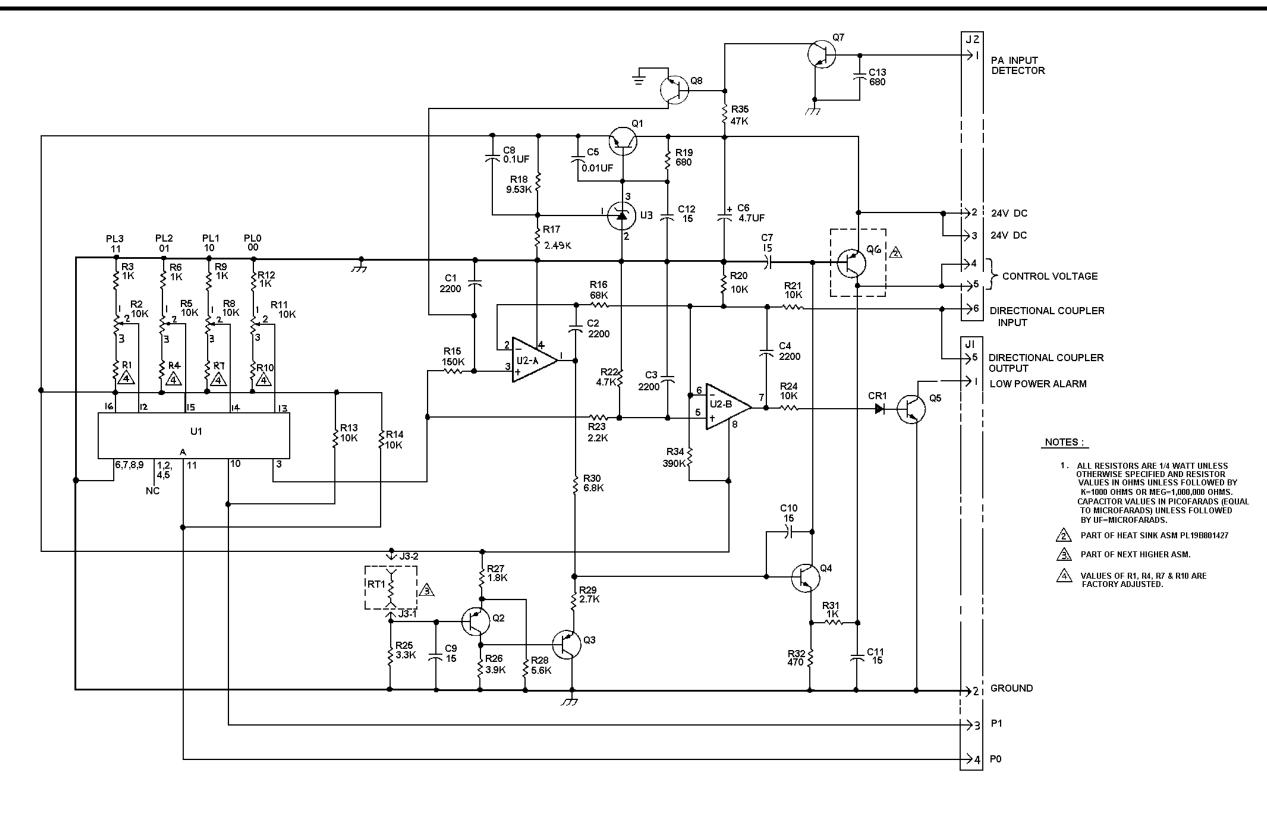
TOP VIEW

NOTE: CASE SHAPE IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

POWER CONTROL BOARD

19D901803G3

⁽¹⁹D901803, Sh. 1, Rev. 1) (19D902059, Component Side, Rev. 1) (19D902059, Solder Side, Rev. 1)



POWER CONTROL BOARD

19D901803G3

MODEL NO. REVISION LETTER
PL19D901803G3 A

(19D902060, Sh. 1, Rev. 11)

LBI-38134

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